

Transistors with Built-in Resistor DRA3144V0L

DRA3144V0L

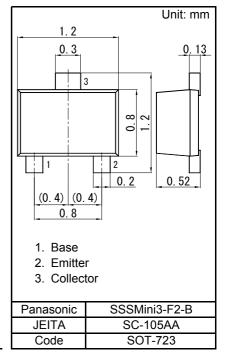
Silicon PNP epitaxial planar type

For digital circuits Complementary to DRC3144V DRA9144V in SSSMini3 type package

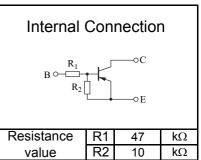
Features

- Low collector-emitter saturation voltage Vce(sat)
- Halogen-free / RoHS compliant (EU RoHS / UL-94 V-0 / MSL:Level 1 compliant)
- Marking Symbol: LJ
- Packaging

Embossed type (Thermo-compression sealing) : 10 000 pcs / reel (standard)



Symbol	Rating	Unit
VCBO	-50	V
VCEO	-50	V
IC	-100	mA
PT	100	mW
Tj	150	°C
Topr	-40 to +85	°C
Tstg	-55 to +150	°C
	VCBO VCEO IC PT Tj Topr	VCBO -50 VCEO -50 IC -100 PT 100 Tj 150 Topr -40 to +85



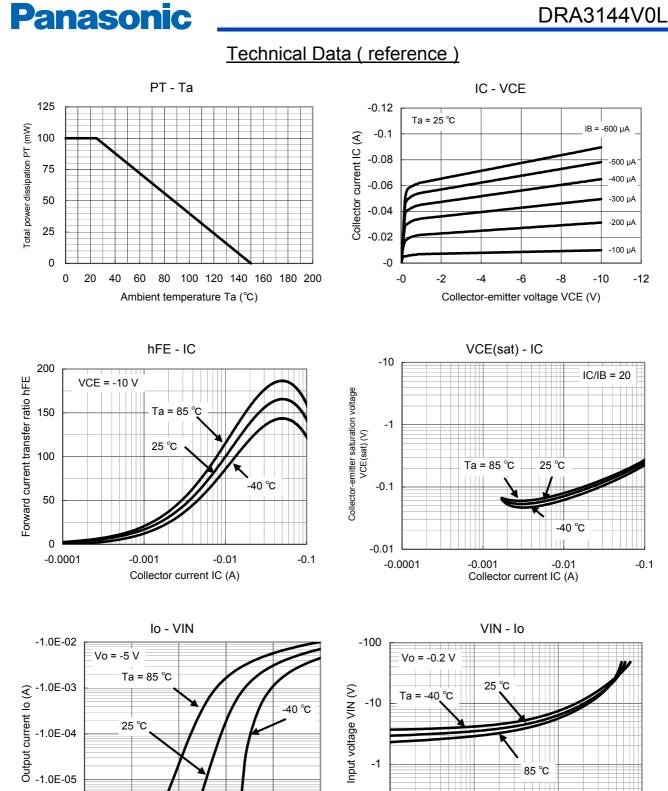
Electrical Characteristics	Ta = 25 °C ± 3 °C
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Absolute Maximum Ratings Ta = 25 °C

Parameter	Symbol	Conditions	Min	Тур	Max	Unit
Collector-base voltage (Emitter open)	VCBO	IC = -10 μA, IE = 0	-50			V
Collector-emitter voltage (Base open)	VCEO	IC = -2 mA, IB = 0	-50			V
Collector-base cutoff current (Emitter open)	ICBO	VCB = -50 V, IE = 0			-0.1	μA
Collector-emitter cutoff current (Base open)	ICEO	VCE = -50 V, IB = 0			-0.5	μA
Emitter-base cutoff current (Collector open)	IEBO	VEB = -6 V, IC = 0			-0.2	mA
Forward current transfer ratio	hFE	VCE = -10 V, IC = -5 mA	30			-
Collector-emitter saturation voltage	VCE(sat)	IC = -10 mA, IB = -0.5 mA			-0.25	V
Input voltage	Vi(on)	VCE = -0.2 V, IC = -5 mA	-6.3			V
	Vi(off)	VCE = -5 V, IC = -100 μA			-1.9	V
Input resistance	R1		-30%	47	+30%	kΩ
Resistance ratio	R1/R2		3.7	4.7	5.7	-

Note) 1. Measuring methods are based on JAPANESE INDUSTRIAL STANDARD JIS C 7030 Measuring methods for transistors.

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-0.1

-0.0001

-0.001

Output current Io (A)

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-0.1

-0.01

Established : 2009-10-23 Revised : 2014-02-18

-1.0E-06

-0

-1

-2

Input voltage VIN (V)

-3

-4

-5



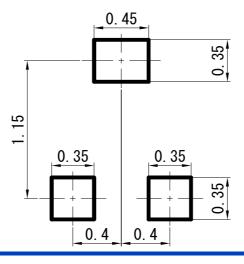
SSSMini3-F2-B

Transistors with Built-in Resistor DRA3144V0L

Unit: mm

1.20 ± 0.05 0.13-0.02 **0. 30**^{+0. 05} 0. 02 3 0.80±0.05 1.20 ± 0.05 20 2 1 **0. 20**+0. 05 -0. 02 0.20 ± 0.05 (0.4) (0.4) 0.80 ± 0.05 (5°) 27) 52 ± 0.03 ġ o' 0 to 0.05

Land Pattern (Reference) (Unit: mm)



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Established : 2009-10-23 Revised : 2014-02-18

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